

EPS13D2 C 2 J E -18.432M

Series -RoHS Compliant (Pb-free) 3.3V 4 Pad 5mm x 7mm Ceramic SMD LVCMOS Programmable Spread Spectrum Oscillator

Nominal Frequency 18.432MHz

L Spread Spectrum ±1.50% Center Spread **Output Control Function**

Power Down

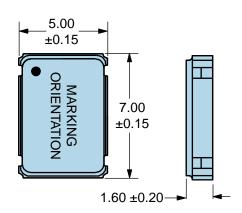
Duty Cycle -50 ±5%

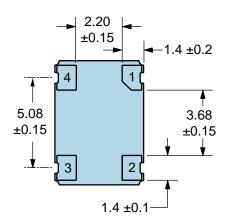
ELECTRICAL SPECIFICAT	TIONS CONTRACTOR OF THE PROPERTY OF THE PROPER	
Nominal Frequency	18.432MHz	
Frequency Stability	±100ppm Maximum over Operating Temperature of -20°C to +70°C (Inclusive of all conditions: Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration.)	
Aging at 25°C	±5ppm First Year Maximum	
Supply Voltage	3.3Vdc ±0.3Vdc	
Maximum Supply Voltage	-0.5Vdc to +7.0Vdc	
Input Current	30mA Maximum (Unloaded; Vdd=3.3Vdc)	
Output Voltage Logic High (Voh)	Vdd-0.4Vdc Minimum (IOH=-8mA)	
Output Voltage Logic Low (Vol)	0.4Vdc Maximum (IOL=+8mA)	
Rise/Fall Time	2.7nSec Maximum (Measured at 20% to 80% of Waveform)	
Duty Cycle	50 ±5% (Measured at 50% of Waveform)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Output Control Function	Power Down (High Impedance Internal Pull Down Resistor of 100kOhms Typical on Pad 3, Internal Pull Up Resistor of 100kOhms Typical on Pad 1)	
Power Down Input Voltage (Vih and Vil)	70% of Vdd Minimum or No Connection to Enable Output, 30% of Vdd Maximum to Disable Output	
Power Down Output Disable Time	350nSec Maximum	
Power Down Output Enable Time	3mSec Maximum	
Standby Current	50μA Maximum (Unloaded; Pad 1=Ground; Vdd=3.3Vdc)	
Spread Spectrum	±1.50% Center Spread	
Modulation Frequency	30kHz Minimum, 31.5kHz Typical, 33kHz Maximum	
Period Jitter	700pSec Maximum (Cycle to Cycle; Spread Spectrum-On; Vdd=3.3Vdc)	
Start Up Time	10mSec Maximum	
Storage Temperature Range	-55°C to +125°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Mechanical Shock	MIL-STD-202, Method 213, Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010	
Vibration	MIL-STD-883, Method 2007, Condition A	



MECHANICAL DIMENSIONS (all dimensions in millimeters)



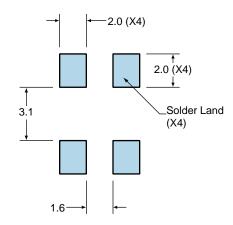


PIN	CONNECTION	
1	Power Down	
2	Case/Ground	
3	Output	
4	Supply Voltage	

LINE	MARKING
1	ECLIPTEK
2	18.432M
3	SXXYZZ S=Configuration Designatol XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year

Suggested Solder Pad Layout

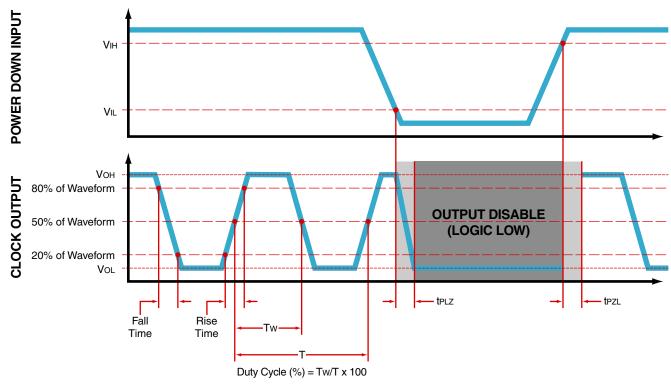
All Dimensions in Millimeters



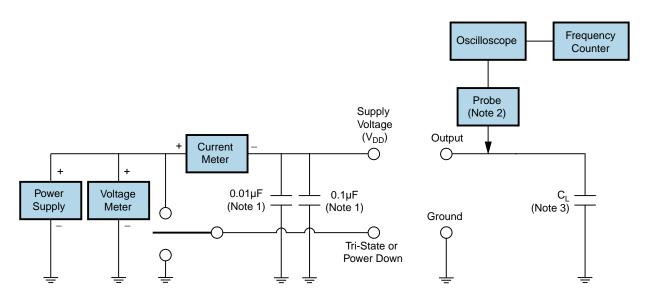
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



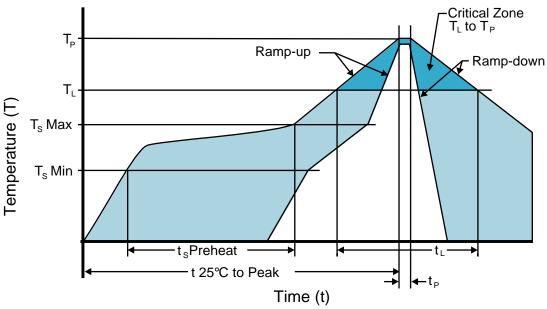
Test Circuit for CMOS Output



- Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods

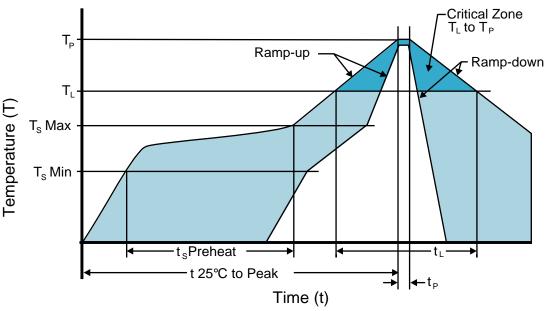


High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t _p)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.